### 1. General description

The 74AHC30-Q100; 74AHCT30-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7-A.

The 74AHC30-Q100; 74AHCT30-Q100 provides an 8-input NAND function.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- · Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Inputs accept voltages higher than V<sub>CC</sub>
- Input levels:
  - For 74AHC30-Q100: CMOS level
  - For 74AHCT30-Q100: TTL level
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

# 3. Ordering information

**Table 1. Ordering information** 

| Type number                       | Package           |          |  |                 |
|-----------------------------------|-------------------|----------|--|-----------------|
|                                   | Temperature range | Name     | Description  | Version         |
| 74AHC30D-Q100<br>74AHCT30D-Q100   | -40 °C to +125 °C | SO14     | plastic small outline package; 14 leads;<br>body width 3.9 mm  | SOT108-1        |
| 74AHC30PW-Q100<br>74AHCT30PW-Q100 | -40 °C to +125 °C | TSSOP14  | plastic thin shrink small outline package; 14 leads; body width 4.4 mm   | SOT402-1        |
| 74AHC30BQ-Q100<br>74AHCT30BQ-Q100 | -40 °C to +125 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm | <u>SOT762-1</u> |

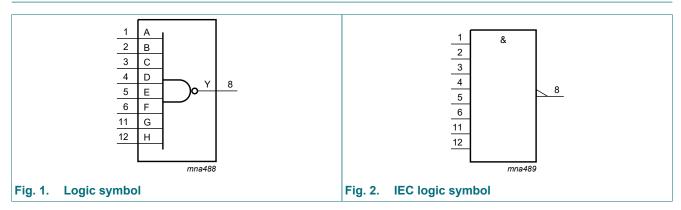


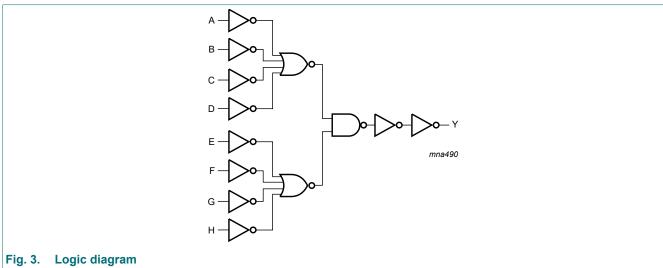
# 4. Marking

Table 2. Marking codes

| Type number     | Marking   |
|-----------------|-----------|
| 74AHC30D-Q100   | 74AHC30D  |
| 74AHCT30D-Q100  | 74AHCT30D |
| 74AHC30PW-Q100  | AHC30     |
| 74AHCT30PW-Q100 | AHCT30    |
| 74AHC30BQ-Q100  | AHC30     |
| 74AHCT30BQ-Q100 | AHT30     |

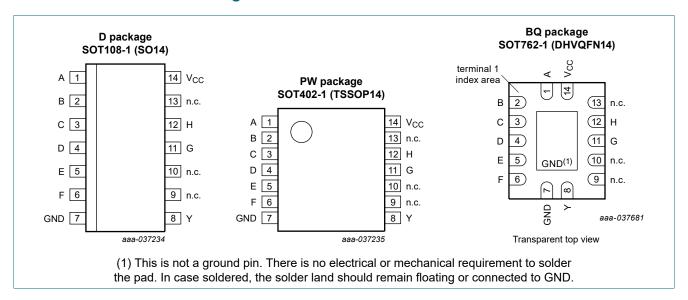
# 5. Functional diagram





# 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| A               | 1   | data input     |
| В               | 2   | data input     |
| С               | 3   | data input     |
| D               | 4   | data input     |
| E               | 5   | data input     |
| F               | 6   | data input     |
| GND             | 7   | ground (0 V)   |
| Υ               | 8   | data output    |
| n.c.            | 9   | not connected  |
| n.c.            | 10  | not connected  |
| G               | 11  | data input     |
| Н               | 12  | data input     |
| n.c.            | 13  | not connected  |
| V <sub>CC</sub> | 14  | supply voltage |

# 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$ 

| Input |   |   |   |   |   |   |   | Output |
|-------|---|---|---|---|---|---|---|--------|
| Α     | В | С | D | E | F | G | Н | Y      |
| L     | Х | Х | Х | Х | Х | Х | Х | Н      |
| Χ     | L | Х | Х | Х | Х | Х | Х | Н      |
| Χ     | Х | L | Х | Х | Х | Х | Х | Н      |
| Χ     | Х | Х | L | Х | Х | Х | Х | Н      |
| Χ     | Х | Х | Х | L | Х | Х | Х | Н      |
| Χ     | Х | Х | Х | Х | L | Х | Х | Н      |
| Χ     | Х | Х | Х | Х | Х | L | Х | Н      |
| X     | Х | Х | Х | Х | Х | Х | L | Н      |
| Н     | Н | Н | Н | Н | Н | Н | Н | L      |

# 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions   |     | Min  | Max  | Unit |
|------------------|-------------------------|--|-----|------|------|------|
| V <sub>CC</sub>  | supply voltage          |  |     | -0.5 | +7.0 | V    |
| VI               | input voltage           |  |     | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V                                      | [1] | -20  | -    | mA   |
| I <sub>OK</sub>  | output clamping current | $V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$  | [1] | -20  | +20  | mA   |
| Io               | output current          | $V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$        |     | -25  | +25  | mA   |
| I <sub>CC</sub>  | supply current          |  |     | -    | +75  | mA   |
| I <sub>GND</sub> | ground current          |  |     | -75  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |  |     | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C                         |     |      |      |      |
|                  |                         | SOT108-1 (SO14)<br>SOT402-1 (TSSOP14)<br>SOT762-1 (DHVQFN14) | [2] | -    | 500  | mW   |

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>[2]</sup> For SOT108-1 (SO14) package: P<sub>tot</sub> derates linearly with 10.1 mW/K above 100 °C. For SOT402-1 (TSSOP14) package: P<sub>tot</sub> derates linearly with 7.3 mW/K above 81 °C. For SOT762-1 (DHVQFN14) package: P<sub>tot</sub> derates linearly with 9.6 mW/K above 98 °C.

# 9. Recommended operating conditions

### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter             | Parameter Conditions                       |     | 74AHC30-Q100 |                 |     | 74AHCT30-Q100 |                 |      |
|------------------|-----------------------|--|-----|--------------|-----------------|-----|---------------|-----------------|------|
|                  |                       |  | Min | Тур          | Max             | Min | Тур           | Max             |      |
| V <sub>CC</sub>  | supply voltage        |  | 2.0 | 5.0          | 5.5             | 4.5 | 5.0           | 5.5             | V    |
| VI               | input voltage         |  | 0   | -            | 5.5             | 0   | -             | 5.5             | V    |
| Vo               | output voltage        |  | 0   | -            | V <sub>CC</sub> | 0   | -             | V <sub>CC</sub> | V    |
| T <sub>amb</sub> | ambient temperature   |  | -40 | +25          | +125            | -40 | +25           | +125            | °C   |
| Δt/ΔV            | input transition rise | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ | -   | -            | 100             | -   | -             | -               | ns/V |
|                  | and fall rate         | $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | -   | -            | 20              | -   | -             | 20              | ns/V |

### 10. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                  | Conditions   |      | 25 °C |      | -40 °C to | o +85 °C | -40 °C to +125 °C |      | Unit |
|-----------------|----------------------------|--|------|-------|------|-----------|----------|-------------------|------|------|
|                 |                            |  | Min  | Тур   | Max  | Min       | Max      | Min               | Max  | 1    |
| 74AHC3          | 0-Q100                     |  |      |       |      |           |          |                   |      |      |
| V <sub>IH</sub> | HIGH-level                 | V <sub>CC</sub> = 2.0 V  | 1.5  | -     | -    | 1.5       | -        | 1.5               | -    | V    |
|                 | input voltage              | V <sub>CC</sub> = 3.0 V  | 2.1  | -     | -    | 2.1       | -        | 2.1               | -    | V    |
|                 |                            | V <sub>CC</sub> = 5.5 V  | 3.85 | -     | -    | 3.85      | -        | 3.85              | -    | V    |
| V <sub>IL</sub> | LOW-level                  | V <sub>CC</sub> = 2.0 V  | -    | -     | 0.5  | -         | 0.5      | -                 | 0.5  | V    |
|                 | input voltage              | V <sub>CC</sub> = 3.0 V  | -    | -     | 0.9  | -         | 0.9      | -                 | 0.9  | V    |
|                 |                            | V <sub>CC</sub> = 5.5 V  | -    | -     | 1.65 | -         | 1.65     | -                 | 1.65 | V    |
| V <sub>OH</sub> | / <sub>OH</sub> HIGH-level | $V_I = V_{IH}$ or $V_{IL}$                                       |      |       |      |           |          |                   |      |      |
|                 | output voltage             | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V                 | 1.9  | 2.0   | -    | 1.9       | -        | 1.9               | -    | V    |
|                 |                            | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 3.0 V                 | 2.9  | 3.0   | -    | 2.9       | -        | 2.9               | -    | V    |
|                 |                            | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V                 | 4.4  | 4.5   | -    | 4.4       | -        | 4.4               | -    | V    |
|                 |                            | $I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V                              | 2.58 | -     | -    | 2.48      | -        | 2.40              | -    | V    |
|                 |                            | $I_{O}$ = -8.0 mA; $V_{CC}$ = 4.5 V                              | 3.94 | -     | -    | 3.80      | -        | 3.70              | -    | V    |
| V <sub>OL</sub> | LOW-level                  | $V_I = V_{IH}$ or $V_{IL}$                                       |      |       |      |           |          |                   |      |      |
|                 | output voltage             | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V                  | -    | 0     | 0.1  | -         | 0.1      | -                 | 0.1  | V    |
|                 |                            | $I_{O} = 50 \mu A; V_{CC} = 3.0 V$                               | -    | 0     | 0.1  | -         | 0.1      | -                 | 0.1  | V    |
|                 |                            | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V                  | -    | 0     | 0.1  | -         | 0.1      | -                 | 0.1  | V    |
|                 |                            | $I_{O}$ = 4.0 mA; $V_{CC}$ = 3.0 V                               | -    | -     | 0.36 | -         | 0.44     | -                 | 0.55 | V    |
|                 |                            | I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V                 | -    | -     | 0.36 | -         | 0.44     | -                 | 0.55 | V    |
| I <sub>I</sub>  | input leakage<br>current   | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V | -    | -     | 0.1  | -         | 1.0      | -                 | 2.0  | μΑ   |
| I <sub>CC</sub> | supply current             | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -     | 2.0  | -         | 20       | -                 | 40   | μΑ   |
| C <sub>I</sub>  | input<br>capacitance       | V <sub>I</sub> = V <sub>CC</sub> or GND                          | -    | 3     | 10   | -         | 10       | -                 | 10   | pF   |
| Co              | output<br>capacitance      |  | -    | 4     | -    | -         | -        | -                 | -    | pF   |

| Symbol                     | Parameter                                     | Conditions  |      | 25 °C |      | -40 °C t | o +85 °C | -40 °C to | +125 °C  | Unit |
|----------------------------|---|---|------|-------|------|----------|----------|-----------|----------|------|
|                            |   |   | Min  | Тур   | Max  | Min      | Max      | Min       | Max      |      |
| 74AHCT                     | 30-Q100                                       |   |      |       |      |          |          | <u>'</u>  | <u>'</u> | '    |
| V <sub>IH</sub>            | HIGH-level input voltage                      | V <sub>CC</sub> = 4.5 V to 5.5 V  | 2.0  | -     | -    | 2.0      | -        | 2.0       | -        | V    |
| V <sub>IL</sub>            | LOW-level input voltage                       | V <sub>CC</sub> = 4.5 V to 5.5 V  | -    | -     | 0.8  | -        | 0.8      | -         | 0.8      | V    |
| V <sub>OH</sub> HIGH-level | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$ |   |      |       |      |          |          |           |          |      |
|                            | output voltage                                | Ι <sub>Ο</sub> = -50 μΑ   | 4.4  | 4.5   | -    | 4.4      | -        | 4.4       | -        | V    |
|                            |   | I <sub>O</sub> = -8.0 mA  | 3.94 | -     | -    | 3.80     | -        | 3.70      | -        | V    |
| V <sub>OL</sub>            |   | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$   |      |       |      |          |          |           |          |      |
|                            | output voltage                                | Ι <sub>Ο</sub> = 50 μΑ  | -    | 0     | 0.1  | -        | 0.1      | -         | 0.1      | V    |
|                            |   | I <sub>O</sub> = 8.0 mA   | -    | -     | 0.36 | -        | 0.44     | -         | 0.55     | V    |
| I <sub>I</sub>             | input leakage<br>current                      | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V  | -    | -     | 0.1  | -        | 1.0      | -         | 2.0      | μΑ   |
| I <sub>CC</sub>            | supply current                                | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$  | -    | -     | 2.0  | -        | 20       | -         | 40       | μΑ   |
| ΔI <sub>CC</sub>           | additional<br>supply current                  | per input pin;<br>$V_I = V_{CC} - 2.1 \text{ V}$ ; other pins<br>at $V_{CC}$ or GND; $I_O = 0 \text{ A}$ ;<br>$V_{CC} = 4.5 \text{ V}$ to 5.5 V | -    | -     | 1.35 | -        | 1.5      | -         | 1.5      | mA   |
| C <sub>I</sub>             | input<br>capacitance                          | V <sub>I</sub> = V <sub>CC</sub> or GND   | -    | 3     | 10   | -        | 10       | -         | 10       | pF   |
| Co                         | output<br>capacitance                         |   | -    | 4     | -    | -        | -        | -         | -        | pF   |

# 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

|                 |                                     | ·=   |        |        |          |                |           |          |                   |      |          |  |
|-----------------|-------------------------------------|--|--------|--------|----------|----------------|-----------|----------|-------------------|------|----------|--|
| Symbol          | Parameter                           | Conditions   |        |        | 25 °C    |                | -40 °C to | o +85 °C | -40 °C to +125 °C |      | Unit     |  |
|                 |                                     |  |        | Min    | Typ[1]   | Max            | Min       | Max      | Min               | Max  |          |  |
| 74AHC3          | 0-Q100                              |  |        |        | <u>'</u> |                | ,         | ,        | ,                 | '    | <u>'</u> |  |
| t <sub>pd</sub> | propagation                         | A, B, C, D, E, F, G, H to Y; see <u>Fig. 4</u> and <u>Fig. 5</u> [2] |        |        |          |                |           |          |                   |      |          |  |
|                 | delay                               | V <sub>CC</sub> = 3.0 V to 3.6 V                                     |        |        |          |                |           |          |                   |      |          |  |
|                 |                                     | C <sub>L</sub> = 15 pF   |        | -      | 5.0      | 9.5            | 1.0       | 11.0     | 1.0               | 12.0 | ns       |  |
|                 |                                     | C <sub>L</sub> = 50 pF   |        | -      | 6.7      | 12.0           | 1.0       | 14.5     | 1.0               | 15.5 | ns       |  |
|                 | V <sub>CC</sub> = 4.5 V to 5.5 V    |  |        |        |          |                |           |          |                   |      |          |  |
|                 |                                     | C <sub>L</sub> = 15 pF   |        | -      | 3.6      | 6.5            | 1.0       | 7.5      | 1.0               | 8.0  | ns       |  |
|                 |                                     | C <sub>L</sub> = 50 pF   |        | -      | 4.9      | 8.0            | 1.0       | 9.5      | 1.0               | 10.5 | ns       |  |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | f <sub>i</sub> = 1 MHz;<br>V <sub>I</sub> = GND to V <sub>CC</sub>   | [3]    | -      | 10       | -              | -         | -        | -                 | -    | pF       |  |
| 74AHCT          | 30-Q100; V <sub>CC</sub>            | = 4.5 V to 5.5 V   |        |        | •        |                |           |          |                   |      |          |  |
| t <sub>pd</sub> | propagation                         | A, B, C, D, E, F, G, H to  | /; see | Fig. 4 | and Fig  | <u>. 5</u> [2] |           |          |                   |      |          |  |
|                 | delay                               | C <sub>L</sub> = 15 pF   |        | -      | 3.3      | 6.5            | 1.0       | 7.5      | 1.0               | 8.0  | ns       |  |
|                 |                                     | C <sub>L</sub> = 50 pF   |        | -      | 4.7      | 8.5            | 1.0       | 9.5      | 1.0               | 10.5 | ns       |  |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | $f_i$ = 1 MHz;<br>$V_I$ = GND to $V_{CC}$                            | [3]    | -      | 12       | -              | -         | -        | -                 | -    | pF       |  |

Typical values are measured at nominal supply voltage ( $V_{CC} = 3.3 \text{ V}$  and  $V_{CC} = 5.0 \text{ V}$ ).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

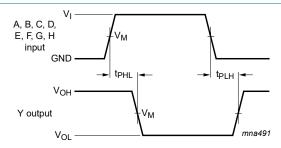
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

 $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

### 11.1. Waveforms



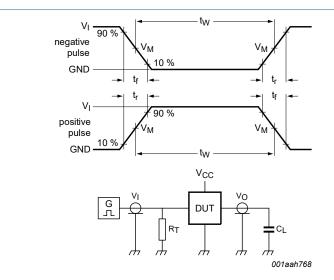
Measurement points are given in Table 9.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Fig. 4. Input to output propagation delays

**Table 9. Measurement points** 

| Туре          | Input                 | Output                |
|---------------|-----------------------|-----------------------|
|               | V <sub>M</sub>        | V <sub>M</sub>        |
| 74AHC30-Q100  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 74AHCT30-Q100 | 1.5 V                 | 0.5 × V <sub>CC</sub> |



Test data is given in Table 10.

Definitions for test circuit:

 $R_T$  = termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator;

 $C_L$  = load capacitance including jig and probe capacitance.

Fig. 5. Test circuit for measuring switching times

Table 10. Test data

| Туре          | Input L         |                                 | Input        |                                     | Load | Test |
|---------------|-----------------|---------------------------------|--------------|-------------------------------------|------|------|
|               | VI              | t <sub>r</sub> , t <sub>f</sub> | CL           |                                     |      |      |
| 74AHC30-Q100  | V <sub>CC</sub> | ≤ 3.0 ns                        | 15 pF, 50 pF | t <sub>PLH</sub> , t <sub>PHL</sub> |      |      |
| 74AHCT30-Q100 | 3.0 V           | ≤ 3.0 ns                        | 15 pF, 50 pF | t <sub>PLH</sub> , t <sub>PHL</sub> |      |      |

**Product data sheet** 

# 12. Package outline

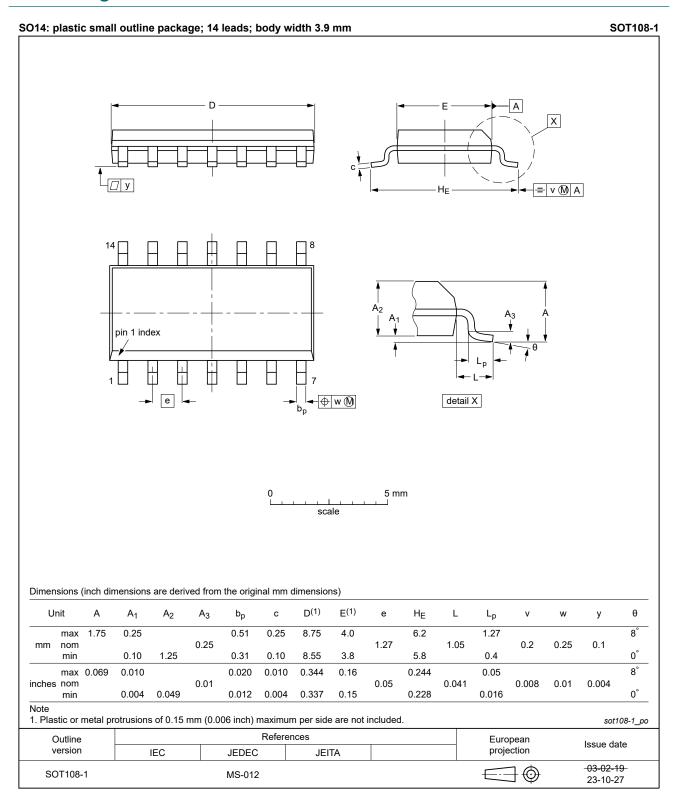


Fig. 6. Package outline SOT108-1 (SO14)

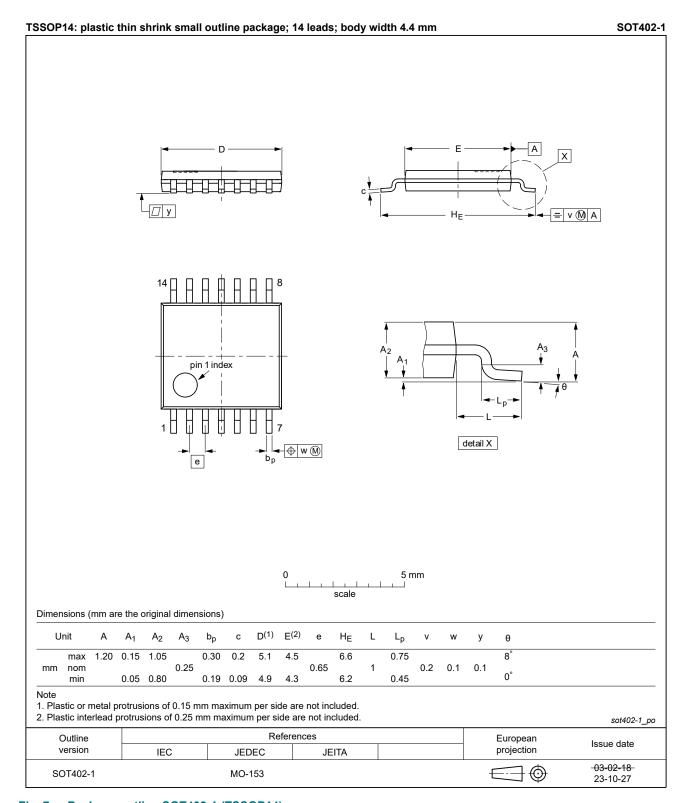


Fig. 7. Package outline SOT402-1 (TSSOP14)

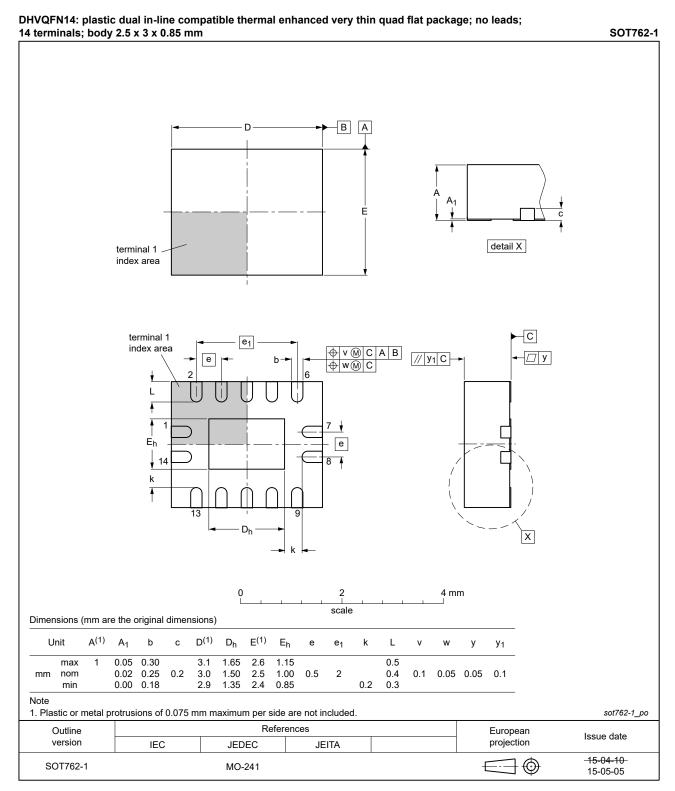


Fig. 8. Package outline SOT762-1 (DHVQFN14)

# 13. Abbreviations

#### **Table 11. Abbreviations**

| Acronym | Description                                    |
|---------|--|
| CDM     | Charged Device Model                           |
| CMOS    | Complementary Metal-Oxide Semiconductor        |
| DUT     | Device Under Test                              |
| ESD     | ElectroStatic Discharge                        |
| HBM     | Human Body Model                               |
| LSTTL   | Low-power Schottky Transistor-Transistor Logic |

# 14. Revision history

### **Table 12. Revision history**

| Table 12. Novicion microry |   |                    |               |                       |  |
|----------------------------|---|--------------------|---------------|-----------------------|--|
| Document ID                | Release date  | Data sheet status  | Change notice | Supersedes            |  |
| 74AHC_AHCT30_Q100 v.4      | 20240307  | Product data sheet | -             | 74AHC_AHCT30_Q100 v.3 |  |
| Modifications:             | <ul> <li>Fig. 6, Fig. 7: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and<br/>MO-153.</li> </ul>   |                    |               |                       |  |
| 74AHC_AHCT30_Q100 v.3      | 20231009  | Product data sheet | -             | 74AHC_AHCT30_Q100 v.2 |  |
| Modifications:             | <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.  |                    |               |                       |  |
| 74AHC_AHCT30_Q100 v.2      | 20200506  | Product data sheet | -             | 74AHC_AHCT30_Q100 v.1 |  |
| Modifications:             | <ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Table 5: Derating values for P<sub>tot</sub> total power dissipation have been updated.</li> <li>Package outline drawing of SOT762-1 (Fig. 8) updated.</li> </ul> |                    |               |                       |  |
| 74AHC_AHCT30_Q100 v.1      | 20131120  | Product data sheet | -             | -                     |  |

### 15. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
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### **Contents**

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 7 March 2024

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